



A model for polycrystalline shape-memory alloys derived from microscopically motivated assumptions

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Views on shape-memory alloys

Microscopic picture



Macroscopic picture



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Macroscopic picture



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On the microscopic level, we have

 \circ high temperature:

atomic grid with high symmetry (usually cubic): the so-called austenite, higher heat capacity

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atomic grid with lower symmetry: martensite, lower heat capacity typically in many symmetry-related variants;



 Microstructure particularly appears on the austenite martensite interface



Microscopic picture





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 One could start the phenomenological modelling "just" from the available measurement



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→ see Petr Sedlák's talk for more experimental data

- 1. We need to model the hysteretic (inelastic) stress-strain behavior
- 2. The designed model needs to be simple, should allow for computations even on large specimens
- Detailed knowledge of the processes on the microscopic level is not necessary (but we will need to reflect the microscopic knowledge)

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\rightsquigarrow puts us into the setting of irreversible thermodynamics

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A prototypical non-elastic behavior is plasticity



- ► The modelling ansatz (small-strain setting) is to divide the strain into its elastic and plastic part: ε = ε^{el} + εⁱⁿ
- ► The stress σ (given e.g. by σ = Ce^{el}) is confined to a ball (region of elasticity)
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The inelastic material properties are described by the inner variable and the main constitutive quantity for their modelling is the "shape" of the region of elasticity

A number of models for polycrystalline shape-memory alloys have been designed building up on a similar principle:

1. The inner variables are

 $\varepsilon^{\rm tr}$ (transformation strain) OR ξ (volume frac. of mart.) and $\varepsilon^{\rm tr}$

2. The stress is given by $\sigma = \frac{d\varphi}{d\varepsilon^{el}}$ with

$$\phi = \underbrace{\frac{1}{2} \varepsilon^{\text{el}} \mathbb{C}(\xi) \varepsilon^{\text{el}}}_{\text{elastic part}} + \underbrace{\xi f^{A}(T) + (1 - \xi) f^{M}(T)}_{\text{chemical part}} + \underbrace{\cdots}_{\text{hardening,...}}$$
$$= \frac{1}{2} \varepsilon^{\text{el}} \mathbb{C}(\xi) \varepsilon^{\text{el}} + \Delta s^{AM} (T - T_{0}) \xi$$
$$+ u_{0}^{A} - s_{0}^{A} T + c^{A} \left[(T - T_{0}) - T \ln \left(\frac{T}{T_{0}} \right) \right]$$

3. A region of elasticity or "dissipative forces" are prescribed

[Auricchio, Petrini, 2004], [Chemisky et al; 2011], [Panico, Brinson, 2007], [Sadjapour, Bhattacharya; 2007]

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The region of elasticity is of a high dimension (tensor as inner variable)

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maybe a different ("scalar") modelling approach?

Generalized standard materials (GSM)

The constitutive properties of the material are encoded in two scalar potentials:

> $\phi(\varepsilon, \xi, \varepsilon^{\mathrm{tr}})$ energy $d(\varepsilon, \xi, \varepsilon^{\mathrm{tr}}, \dot{\xi}, \dot{\varepsilon}^{\mathrm{tr}})$ dissipation potential

The generalized thermodynamic forces are given by

$$\mathsf{A} \in \partial_{\dot{\xi}, \dot{\varepsilon}^{\mathrm{tr}}} \mathsf{d}(\varepsilon, \xi, \varepsilon^{\mathrm{tr}}, \dot{\xi}, \dot{\varepsilon}^{\mathrm{tr}})$$

 To ensure thermodanymical consistency (second law of thermodynamics) the dissipation potential is convex and zero for zero rates

Plasticity in the GSM network

For von-Mises plasticity we set

$$egin{aligned} \phi(arepsilon,arepsilon_{ ext{pl}}) &= rac{1}{2}arepsilon_{ ext{el}} \mathbb{C}arepsilon_{ ext{el}} \ d(\dot{arepsilon}_{ ext{pl}}) &= lpha |\dot{arepsilon}_{ ext{pl}}| \end{aligned}$$

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► The dissipation potential is homogeneous of degree 1 ~→ corresponds to an rate-independent (activated) process

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We will restrict our modelling only to rate-independent processes in shape-memory alloys

For our modelling we will use yet another approach and define

$$\delta(\alpha_A, \alpha_B) := \inf \left\{ \int_{\alpha_A \to \alpha_B} d(\alpha, \dot{\alpha}) \, \mathrm{d}\Gamma; \text{ over all smooth paths from} \\ \alpha_A \text{ to } \alpha_B \right\}$$

a dissipation distance between two states α_A, α_B

Since the dissipation is independent of the speed, we can find a path that leads to minimal dissipation between two states \rightsquigarrow this defines the dissipation distance

For our modelling we will use yet another approach and define

$$\delta(\alpha_A, \alpha_B) := \inf \Big\{ \int_{\alpha_A \to \alpha_B} d(\alpha, \dot{\alpha}) \, \mathrm{d}\Gamma; \text{ over all smooth paths from} \\ \alpha_A \text{ to } \alpha_B \Big\}$$

- a dissipation distance between two states α_A, α_B
 - If the dissipation distance is derived from a potential, we have that

$$d(\alpha, \dot{\alpha}) = \lim_{\epsilon \to 0^+} \frac{1}{\epsilon} \delta(\alpha, \alpha + \epsilon \dot{\alpha})$$

(but otherwise the "reverse" relation is unclear)

For our modelling we will use yet another approach and define

$$\delta(lpha_A, lpha_B) := \inf \left\{ \int_{lpha_A o lpha_B} d(lpha, \dot{lpha}) \,\mathrm{d}\Gamma; \text{ over all smooth paths from} \\ lpha_A ext{ to } lpha_B
ight\}$$

a dissipation distance between two states α_A, α_B For thermodynamical consistency we will need that

•
$$\delta(\cdot, \cdot) \geq 0$$

- δ is convex in the second variable
- it fulfills the triangle inequality

$$\delta(\alpha_{A}, \alpha_{B}) \leq \delta(\alpha_{A}, \alpha_{C}) + \delta(\alpha_{C}, \alpha_{B})$$

for all admissible states of the system α_A , α_B , α_C .

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a dissipation distance between two states $\alpha_{\text{A}}, \alpha_{\text{B}}$

In our modelling, we will see the dissipation distance as the dissipation between two states within a small time increment.
For the inner variables we will take

 $\varepsilon^{in} = \xi \varepsilon^{tr}$ (inelastic strain) AND ξ (volume frac.)

with the constraints

$$\langle \varepsilon^{\mathrm{in}} \rangle \leq \xi \quad \mathsf{AND} \quad 0 \leq \xi \leq 1.$$

 \rightsquigarrow this corresponds to the fact that only some microstructures can be reached without elasticity

For the energy we take the standard form

$$\phi = \underbrace{\frac{1}{2} \varepsilon^{\mathrm{el}} \mathbb{C}(\xi) \varepsilon^{\mathrm{el}}}_{\text{elastic part}} + \underbrace{\xi f^{\mathcal{A}}(\mathcal{T}) + (1 - \xi) f^{\mathcal{M}}(\mathcal{T})}_{\text{chemical part}} + \underbrace{\cdots}_{\text{hardening}, \dots}$$

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This already gives some inspiration from microscopic to macroscopic point of view



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But what is missing is the microstructure formation

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Microscopic picture Macroscopic picture

But what is missing is the microstructure formation

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We will try to take this into account for the dissipation distance

Transformation-favourable martensite

Transformation-favourable martensite-forward

Austenite transforms to martensite always through formation of a particular martensitic structure – transformation favorable martensite (TFM) – that is characterized by zero net macroscopic strain at the moment of creation. Immediate subsequent reorientation of TFM is possible.

Transformation-favourable martensite-reverse

A necessary condition for initialisation of a reverse transformation in any amount of martensite is formation of TFM within it.

Transformation-favourable martensite

What we have in mind....



.... when an austenite-martensite interface is formed, the martensite has to form twins/microstructure at the interface for compatibility.

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Transformation-favourable martensite

However,...

Transformation-favourable martensite-forward

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this is an oversimplification!

On the microscopic level...

 Even for monoclinic SMAs (like NiTi) no twinned structure actually has zero-net strain.

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How can we actually interpret this assumption?

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On the microscopic level...

Averaging...



 in every material point there are many grains with very different microstructures

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On the microscopic level... Averaging...



 in every material point there are many grains with very different microstructures

However, there is no rigorous proof that the average has to be of zero-net strain

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On the microscopic level...

Looking just from the dissipation point of view...

- The assumption is that there is no dissipation connected to reorientation when transforming from austenite to TFM (and back)
- in the simplified case of phenomenological modelling this is achieved by the zero-net strain assumption
- ► ~→ also other phenomenological models assume that the twinned structure is of zero-net inelastic strain

[Lexcellent et al; 2006], [Popov, Lagoudas; 2007]

On the microscopic level...

The best argument is of course that the derived model compares well to experiment

see Petr Sedlák's talk!

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Implications on the dissipation distance

We can split the dissipation distance into a transformation part and a reorientation part:

$$\delta = \delta^{\rm tr} + \delta^{\rm reo}.$$

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Notice: Here this split is a consequence of formation of TFM

[Zaki, Moumni;2009], [Chemisky et al.; 2011]

Transformation part of dissipation distance

Assumption on transformation part of dissipation distance

The transformation part of dissipation distance is proportional to the absolute value of the difference between its initial and final volume fraction of martensite. The positive proportionality factor may depend (linearly) on the volume fraction.

$$\psi$$

$$\delta^{\rm tr}(\xi_A,\xi_B) = c(\xi_A,\xi_B)|\xi_B - \xi_A|$$

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 \rightsquigarrow for thermodynamical consistency (triangle inequality) the form of $c(\xi_A, \xi_B)$ is not arbitrary Here, we take

$$\begin{split} \xi_B \geq \xi_A : \quad \delta^{\mathrm{tr}}(\xi_A, \xi_B) &= \Delta s^{AM} \left[(T_0 - M_{\mathrm{s}}) + \frac{\xi_A + \xi_B}{2} (M_{\mathrm{s}} - M_{\mathrm{f}}) \right] |\xi_B - \xi_A|, \\ \xi_B < \xi_A : \quad \delta^{\mathrm{tr}}(\xi_A, \xi_B) &= \Delta s^{AM} \left[(A_{\mathrm{f}} - T_0) + \frac{\xi_A + \xi_B}{2} (A_{\mathrm{s}} - A_{\mathrm{f}}) \right] |\xi_B - \xi_A|. \end{split}$$

Reorientation part of dissipation distance

Assumption on the reorientation part of the dissipation distance

If martensite is subject to reorientation, the corresponding dissipation distance is proportional to the norm of the difference between its final and initial inelastic strain

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this already allows us to deduce the dissipation when no phase transition is occurring....

Austenite-to-martensite transition

If $\xi_B > \xi_A$ austenite-to-martensite:

► In the small step we look at austenite transforms to TFM ~→ dissipation-free

Additionally other portions of martensite may reorient

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We adopt the assumption that the inelastic strain does not change during the austenite-to-martensite transition \rightsquigarrow this gives the following form of the dissipation distance:

$$\delta^{\text{reo}}(\varepsilon_A^{\text{in}},\xi_A,T_B,\varepsilon_B^{\text{in}},\xi_B) = \sigma^{\text{reo}}(T_B) \|\varepsilon_B^{\text{in}} - \varepsilon_A^{\text{in}}\|.$$

 $\sigma^{\rm reo}(T_B)$ is the proportionality factor

▶ if martensite transforms to austenite (ξ_B < ξ_A), some portion of the inelastic strain has to transform to TFM first (to allow the transition)

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how big are the individual portions?

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how big are the individual portions?

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we assume that the fraction is given by the volume fraction of the disappearing martensite

With this assumptions we arrive at

$$\delta^{\text{reo}}(\varepsilon_{A}^{\text{in}},\xi_{A},T_{B},\varepsilon_{B}^{\text{in}},\xi_{B}) = \underbrace{\sigma^{\text{reo}}(T_{B}) \Big\| \frac{\xi_{A}-\xi_{B}}{\xi_{A}} \varepsilon_{A}^{\text{in}} - 0 \Big\|}_{\text{trf. to TFM}} + \underbrace{\sigma^{\text{reo}}(T_{B}) \Big\| \varepsilon_{B}^{\text{in}} - \frac{\xi_{B}}{\xi_{A}} \varepsilon_{A}^{\text{in}} \Big\|}_{\text{remaining reorient.}}$$

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With this assumptions we arrive at

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remaining reorient.

... or rewriting as

$$\delta^{\rm reo}(\varepsilon_A^{\rm in},\xi_A,T_B,\varepsilon_B^{\rm in},\xi_B) = \sigma^{\rm reo}(T_B) \left[\left\| \frac{\xi_B}{\xi_A} \varepsilon_A^{\rm in} - \varepsilon_A^{\rm in} \right\| + \left\| \varepsilon_B^{\rm in} - \frac{\xi_B}{\xi_A} \varepsilon_A^{\rm in} \right\| \right]$$

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Comments

- ► In addition to the assumption on TFM we had to assume how "big" the portion of inelastic strain is that is due to TFM ~→ complicated microstructure is represented by just one tensor
- During forward transformation the inelastic strain is unchanged

→ *Heuristic idea:* Material can accommodate the transformation, the forward transformation is "preferred"

During reverse transformation the assumption can be also read as: no TFM is in the material, all has to be formed ~ Heuristic idea: Reverse transformation requires more adjustments on microstructure, "is harder"

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- During forward transformation the inelastic strain is unchanged
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- During reverse transformation the assumption can be also read as: no TFM is in the material, all has to be formed ~> Heuristic idea: Reverse transformation requires more adjustments on microstructure, "is harder"

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Nevertheless, also other settings would be compatible with the TFM idea...

Summing up

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Altogether, we have the following energy and dissipation distance in one material point:

$$\begin{split} \phi(T,\varepsilon,\varepsilon^{\mathrm{in}},\xi,\eta) &= \frac{1}{2} K \mathrm{tr}(\varepsilon)^2 + G(\xi,\eta) \| \mathrm{dev}(\varepsilon) - \varepsilon^{\mathrm{in}} \|^2 \\ &+ \Delta s^{AM} (T-T_0) \xi \\ &+ u_0^A - s_0^A T + c^A \left[(T-T_0) - T \ln \left(\frac{T}{T_0} \right) \right], \\ \left\{ \begin{array}{l} c(\xi_A,\xi_b) |\xi_B - \xi_A| &+ \sigma^{\mathrm{reo}} \| \varepsilon_B^{\mathrm{in}} - \varepsilon_A^{\mathrm{in}} \| \\ &\mathrm{if} \ \xi_B \ge \xi_A, \end{array} \right. \\ \left\{ \begin{array}{l} c(\xi_A,\xi_b) |\xi_B - \xi_A| &+ \sigma^{\mathrm{reo}} \| \| \frac{\xi_B}{\xi_A} \varepsilon_A^{\mathrm{in}} - \varepsilon_A^{\mathrm{in}} \| \\ &+ \| \varepsilon_B^{\mathrm{in}} - \frac{\xi_B}{\xi_A} \varepsilon_A^{\mathrm{in}} \| \right] &\mathrm{if} \ \xi_B < \xi_A. \end{split} \end{split}$$

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Thermodynamical consistency

Notice that the proposed dissipation distance

$$\delta(\mathcal{T}, \varepsilon_A^{\mathrm{in}}, \xi_A, \varepsilon_B^{\mathrm{in}}, \xi_B) = \begin{cases} c(\xi_A, \xi_b) |\xi_B - \xi_A| &+ \sigma^{\mathrm{reo}} \|\varepsilon_B^{\mathrm{in}} - \varepsilon_A^{\mathrm{in}}\| \\ & \text{if } \xi_B \ge \xi_A, \end{cases}$$
$$c(\xi_A, \xi_b) |\xi_B - \xi_A| &+ \sigma^{\mathrm{reo}} \Big[\|\frac{\xi_B}{\xi_A} \varepsilon_A^{\mathrm{in}} - \varepsilon_A^{\mathrm{in}}\| \\ &+ \|\varepsilon_B^{\mathrm{in}} - \frac{\xi_B}{\xi_A} \varepsilon_A^{\mathrm{in}}\| \Big] & \text{if } \xi_B < \xi_A. \end{cases}$$

- is non-negative (and zero if no change of state occurs)
- is convex in the B-variables
- satisfies the triangle inequality

Global formulation

The derived energy and dissipation distance hold for one material point. For the whole specimen (Ω) we have to integrate (here u is the underlying deformation and $\alpha := (\varepsilon^{in}, \xi)$ are the dissipative variables):

$$\begin{split} \mathcal{E}(t, u, \alpha) &:= \int_{\Omega} \phi(t, \varepsilon(u), \alpha) + \underbrace{\nu \| \nabla \alpha(t) \|^2}_{\text{regularization term}} - \underbrace{F_{\text{vol}}(t) \cdot u}_{\text{volume force}} \mathrm{d}x \\ &- \int_{\Gamma_{\mathrm{N}}} \underbrace{F_{\text{surf}} \cdot u}_{\text{surface force}} (t) \mathrm{d}S, \end{split}$$

$$egin{aligned} \mathcal{D}(t,lpha, ilde{lpha}) &:= \mathcal{D}^{ ext{tr}}(t,lpha, ilde{lpha}) + \mathcal{D}^{ ext{reo}}(t,lpha, ilde{lpha}) \ &= \int_\Omega \delta^{ ext{tr}}(t,lpha, ilde{lpha}) \mathrm{d} x + \int_\Omega \delta^{ ext{reo}}(t,lpha, ilde{lpha}) \mathrm{d} x. \end{aligned}$$

Global formulation

The variables are limited to the following sets:

$$\mathcal{Q} := ig\{(u, lpha) \in \mathcal{U} imes \mathcal{V} imes \mathcal{Z} \; \; ext{with} \; lpha = (arepsilon^{ ext{in}}, \xi)ig\}$$

where

$$\begin{aligned} \mathcal{U} &:= \{ u \in W^{1,2}(\Omega, \mathbb{R}^3) : u = 0 \text{ on } \Gamma_{\mathrm{D}} \} \\ \mathcal{V} &:= \{ (\varepsilon^{\mathrm{in}}, \xi) \in W^{1,2}(\Omega, \mathbb{R}^{3 \times 3}) \times W^{1,2}(\Omega) : \\ \varepsilon^{\mathrm{in}} \text{ is a traceless, symmetric matrix,} \\ \langle \varepsilon^{\mathrm{in}}(x) \rangle &\leq \xi(x) \text{ for a.a.} x \in \Omega \\ \text{ and } 0 &\leq \xi(x) \leq 1 \text{ for a.a. } x \in \Omega \} \end{aligned}$$

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Global formulation

The variables are limited to the following sets:

$$\mathcal{Q} := \left\{ (u, lpha) \in \mathcal{U} imes \mathcal{V} imes \mathcal{Z} \ \ \text{with} \ lpha = (arepsilon^{ ext{in}}, \xi)
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the triple $(Q, \mathcal{E}, \mathcal{D})$ defines the rate-independent system under consideration

With the energy and dissipation distance given, we can define an an energetic solution for the problem:

- ideally fitted for rate-independent processes
- a global, derivative-free solution concept (avoids subdifferential calculation)
- based on energy conservation and the idea that for any time instant the found state is "the best possible"

Energetic solution

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- ideally fitted for rate-independent processes
- a global, derivative-free solution concept (avoids subdifferential calculation)
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In other words, as soon as a process is admissible from the thermodynamic point of view, it will happen immediately
Definition of an energetic solution

Let \mathcal{E}, \mathcal{D} be given as above and let $(u_0, \alpha_0) \in \mathcal{Q}$. Then triplet $(u(t), \alpha(t), \eta(t)) : [0, \mathcal{T}] \mapsto \mathcal{Q}$ is called an *energetic solution* to the rate-independent system $(\mathcal{Q}, \mathcal{E}, \mathcal{D})$ if $\partial_t \mathcal{E}(t, u(t)) \in L^1([0, \mathcal{T}])$ and if the following conditions are satisfied:

• Stability condition: (for all $(\tilde{u}, \tilde{\alpha}, \tilde{\eta}) \in Q$)

$$\mathcal{E}(t, u(t), \alpha(t), \eta(t)) \leq \mathcal{E}(t, \tilde{u}, \tilde{\alpha}, \tilde{\eta}) + \mathcal{D}(t, \alpha(t), \tilde{\alpha})$$

Energy balance:

$$egin{aligned} &\mathcal{E}(t,u(t),lpha(t),\eta(t)) + \mathrm{Diss}_{\mathcal{D}}(lpha,[0,\mathcal{T}]) \ &=&\mathcal{E}(0,u(0),lpha(0),\eta(0)) + \int_{0}^{\mathcal{T}} \partial_{t}\mathcal{E}(s,u(s)) \mathrm{d}s. \end{aligned}$$

▶ Initial condition: $(u(0), \alpha(0), \eta(0)) = (u_0, \alpha_0, \eta_0)$ a.e. in Ω .

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$$\begin{split} \mathcal{E}(t, u(t), \alpha(t)) + \mathrm{Diss}_{\mathcal{D}}(\alpha, [0, \mathcal{T}]) \\ = \mathcal{E}(0, u(0), \alpha(0)) + \int_{0}^{\mathcal{T}} \partial_{t} \mathcal{E}(s, u(s)) \mathrm{d}s \end{split}$$

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$\operatorname{Diss}_{\mathcal{D}}(\alpha, [0, \mathcal{T}])$ is the overall dissipated energy

► For smooth processes it is given by

$$\mathrm{Diss}_{\mathcal{D}}(\alpha; [0, \mathcal{T}]) = \int_0^{\mathcal{T}} \int_{\Omega} d(t, \alpha(t), \dot{\alpha}(t)) \mathrm{d}x \mathrm{d}t,$$

 $\rightsquigarrow \delta$ is the dissipation potential.

For processes with jumps, we have that

$$\begin{aligned} \text{Diss}^{\text{tr}}(\alpha;[0,\mathcal{T}]) &:= \sup \Big\{ \sum_{i=1}^{N} \mathcal{D}^{\text{tr}}(\alpha(t_{i-1}),\,\alpha(t_{i})) : \\ \text{a.p.p.} \ 0 &= t_{0} \leq t_{1} \leq \ldots \leq t_{N} = \mathcal{T} \Big\}, \end{aligned}$$

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Existence of an energetic solution

Theorem (MF, BB, PS, '14)

Let \mathcal{E}, \mathcal{D} be defined by as above, let the prescribed forces be "sufficiently smooth" and let initial conditions $(u_0, \alpha_0, \eta_0) \in \mathcal{Q}$ satisfy the stability condition. Then there exists an energetic solution of the rate-independent system $(\mathcal{Q}, \mathcal{E}, \mathcal{D})$.

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For the proof, we highlight just some steps...

Time-incremental minimization

Discrete level

We call $(u_{\tau}^k, \alpha_{\tau}^k) \in Q$ a discrete energetic solution to rate-independent system $(Q, \mathcal{E}, \mathcal{D})$ at time-level $k = 1, \ldots, N(\tau)$ if it solves

$$\begin{array}{l} \text{Minimize } \mathcal{E}(t_k, u, \alpha) + \mathcal{D}(t_k, \alpha_{\tau}^{k-1}, \alpha) \\ \text{subject to } (u, \alpha) \in \mathcal{Q} \end{array} \tag{TIP}$$

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with $(u_{\tau}^{0}, \alpha_{\tau}^{0}) = (u_{0}, \alpha_{0}) \in \mathcal{Q}$ defined through the initial condition.

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at every time-step we minimize the energy + *dissipation from the last step*

to assure existence of solutions to (TIP) it is important that *E* and *D* are *convex*

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- for the dissipation distance this comes directly from thermodynamical consistency (*convexity in the second variable*)
- for the energy this is due to the choice of variables

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- for the energy this is due to the choice of variables

Recall the energy function

$$\begin{split} \phi(T,\varepsilon,\varepsilon^{\mathrm{in}},\xi) &= \frac{1}{2} K \mathrm{tr}(\varepsilon)^2 + G(\xi) \| \mathrm{dev}(\varepsilon) - \varepsilon^{\mathrm{in}} \|^2 \\ &+ \Delta s^{AM} (T-T_0) \xi \\ &+ u_0^A - s_0^A T + c^A \left[(T-T_0) - T \ln \left(\frac{T}{T_0} \right) \right], \end{split}$$

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if we used the *transformation strain* instead of the *inelastic* one, we would have

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$$\begin{split} \phi(T,\varepsilon,\varepsilon^{\mathrm{in}},\xi) &= \frac{1}{2} \mathcal{K}\mathrm{tr}(\varepsilon)^2 + G(\xi) \|\mathrm{dev}(\varepsilon) - \xi\varepsilon^{\mathrm{tr}}\|^2 \\ &+ \Delta s^{AM}(T-T_0)\xi \\ &+ u_0^A - s_0^A T + c^A \left[(T-T_0) - T \ln\left(\frac{T}{T_0}\right) \right], \end{split}$$

which is no longer convex...

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- The explicit dependence G = G(ξ) affects the overall convexity of the energy.
- ▶ We use a form $G(\xi) \sim \frac{1}{\xi}$ so that the overall energy is of the form $\frac{y^2}{x} \rightsquigarrow$ convex for $x \ge 0$.

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The time-incremental problem

$$\begin{array}{l} \text{Minimize } \mathcal{E}(t_k, u, \alpha) + \mathcal{D}(t_k, \alpha_{\tau}^{k-1}, \alpha) \\ \text{subject to } (u, \alpha) \in \mathcal{Q} \end{array} \tag{TIP}$$

is also the basis for numerical implementation

[Bourdin; 2007], [Bourdin, Francfort, Marigo; 2008]

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 The numerical implementation is based on alternating minimization - minimization with respect to u (and α fixed) and minimization with respect to α (with u fixed)

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The time-incremental problem

Minimize
$$\mathcal{E}(t_k, u, \alpha) + \mathcal{D}(t_k, \alpha_{\tau}^{k-1}, \alpha)$$

subject to $(u, \alpha) \in \mathcal{Q}$ (TIP)

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 The numerical implementation is based on alternating minimization - minimization with respect to u (and α fixed) and minimization with respect to α (with u fixed)

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This will converge to a critical point (and due to convexity) a minimizer.

[Bourdin; 2007], [Bourdin, Francfort, Marigo; 2008]

The time-incremental problem

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is also the basis for numerical implementation

Advantages of the split:

- 1. The elasticity problem (for *u*) can be solved by standard packages in FEM
- The problem for the inner variables actually splits and can be solved individually for each material (Gauß) point → this allows to use a *derivative-free* method like the Nelder-Mead algorithm

[Bourdin; 2007], [Bourdin, Francfort, Marigo; 2008]

Recall the time-incremental problem

$$\begin{array}{l} \text{Minimize } \mathcal{E}(t_k, u, \alpha,) + \mathcal{D}(t_k, \alpha_{\tau}^{k-1}, \alpha) \\ \text{subject to } (u, \alpha) \in \mathcal{Q} \end{array} \tag{TIP}$$

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From this we obtain the discrete stability condition

$$\mathcal{E}(t_k, u_k, lpha_k,) \leq \mathcal{E}(t_k, ilde{u}, ilde{lpha},) + \mathcal{D}(t_k, lpha_k, ilde{lpha}) \quad orall (ilde{u}, ilde{lpha}) \in \mathcal{Q}$$

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And the energy inequalities

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$$\mathcal{E}(t_k, u_k, \alpha_k,) \leq \mathcal{E}(t_k, \tilde{u}, \tilde{\alpha},) + \mathcal{D}(t_k, \alpha_k, \tilde{\alpha}) \quad \forall (\tilde{u}, \tilde{\alpha}) \in \mathcal{Q}$$

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here it is important that the dissipation distance satisfies the triangle inequality!

Aside: Using the two-sided energy inequality in non-convex problems

In non-convex situations (with many local minima) it is advantageous to verify the energy inequality

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in every step (\rightsquigarrow particularly the "first" inequality)

[B., 2009]

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in every step (\rightsquigarrow particularly the "first" inequality)

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this helps to identify whether the found minimum would not have been optimal already in the last time-step.

[B., 2009]

Aside: Using the two-sided energy inequality in non-convex problems



[B., 2009]

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Convergence

- \blacktriangleright Based on the a-priori estimates we choose convergent sub-sequences for $\tau \rightarrow 0$
- The converges is pointwise for every time-step
- Here we additionally have to cope with the fact that the dissipation distance depends on time (through temperature)

Obtained result

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A numerical calculation



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Reference

Frost, M., Benešová, B., Sedlák, P.: A microscopically motivated constitutive model for shape memory alloys: formulation, analysis and computations, Math. Mech. Solids, 21(3) (2016), 358-382.

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Thank you for your attention!